

CY7C1041G CY7C1041GE

4-Mbit (256K words × 16-bit) Static RAM with Error-Correcting Code (ECC)

Features

- High speed
 - ⊡ t_{AA} = 10 ns/15 ns
- Embedded ECC for single-bit error correction^[1, 2]
- Low active and standby currents
 Active current: I_{CC} = 38 mA typical
 Standby current: I_{SB2} = 6 mA typical
- Operating voltage range: 1.65 V to 2.2 V, 2.2 V to 3.6 V, and 4.5 V to 5.5 V
- 1.0-V data retention
- TTL-compatible inputs and outputs
- Error indication (ERR) pin to indicate 1-bit error detection and correction
- Pb-free 44-pin SOJ, 44-pin TSOP II, and 48-ball VFBGA packages

Functional Description

CY7C1041G and CY7C1041GE are high-performance CMOS fast static RAM devices with embedded ECC. Both devices are offered in single chip-enable option and in multiple pin configurations. The CY7C1041GE device includes an ERR pin that signals an error-detection and correction event during a read cycle.

Data writes are performed by asserting the Chip Enable (\overline{CE}) and Write Enable (\overline{WE}) inputs LOW, while providing the data on I/O₀ through I/O₁₅ and address on A₀ through A₁₇ pins. The Byte High Enable (\overline{BHE}) and Byte Low Enable (\overline{BLE}) inputs control write operations to the upper and lower bytes of the specified memory location. BHE controls I/O₈ through I/O₁₅ and BLE controls I/O₀ through I/O₇.

Data reads are performed by asserting the Chip Enable (\overline{CE}) and Output Enable (\overline{OE}) inputs LOW and providing the required address on the address lines. Read data is accessible on the I/O lines (I/O₀ through I/O₁₅). Byte accesses can be performed by asserting the required byte enable signal (BHE or BLE) to read either the upper byte or the lower byte of data from the specified address location.

All I/Os (I/O $_0$ through I/O $_{15}$) are placed in a high-impedance state during the following events:

- The device is deselected (CE HIGH)
- The control signals (OE, BLE, BHE) are de-asserted

On the CY7C1041GE devices, the detection and correction of a single-bit error in the accessed location is indicated by the assertion of the ERR output (ERR = HIGH)^[1]. See the Truth Table on page 14 for a complete description of read and write modes.

The logic block diagram is on page 2.

Product Portfolio

| Product ^[3] | | | | Speed | | Power Dis | sipation | |
|------------------------|-------------------------------|------------|------------------------------|-------|--------------------|--------------------------|----------------------|---------------------|
| | Features and Options (see Pin | Range | V _{CC} Range (V) | (ns) | Operating | g I _{CC} , (mA) | Standb | y, I _{SB2} |
| | Configurations on page 4) | Range | (V) | 10/15 | f = | f _{max} | (m. | A) |
| | | | | 10/10 | Тур ^[4] | Max | Тур ^[4] М | Max |
| CY7C1041G(E)18 | Single Chip Enable | Industrial | 1.65 V–2.2 V | 15 | - | 40 | 6 | 8 |
| CY7C1041G(E)30 | Optional ERR pins | | 2.2 V–3.6 V | 10 | 38 | 45 | | |
| CY7C1041G(E) | | | 4.5 V–5.5 V | 10 | 38 | 45 | | |

Notes

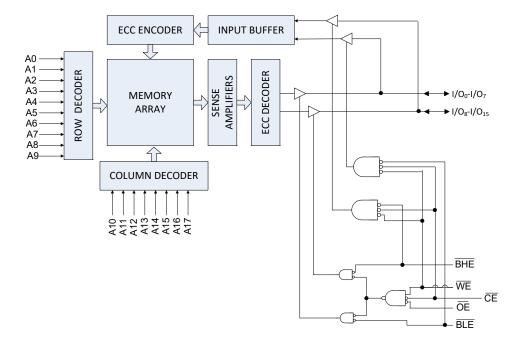
- 1. This device does not support automatic write-back on error detection.
- 2. SER FIT Rate <0.1 FIT/Mb. Refer AN88889 for details.
- 3. The ERR pin is available only for devices which have ERR option "E" in the ordering code. Refer Ordering Information on page 15 for details.
- 4. Typical values are included only for reference and are not guaranteed or tested. Typical values are measured at V_{CC} = 1.8 V (for a V_{CC} range of 1.65 V–2.2 V), V_{CC} = 3 V (for a V_{CC} range of 2.2 V–3.6 V), and V_{CC} = 5 V (for a V_{CC} range of 4.5 V–5.5 V), T_A = 25 °C.

198 Champion Court

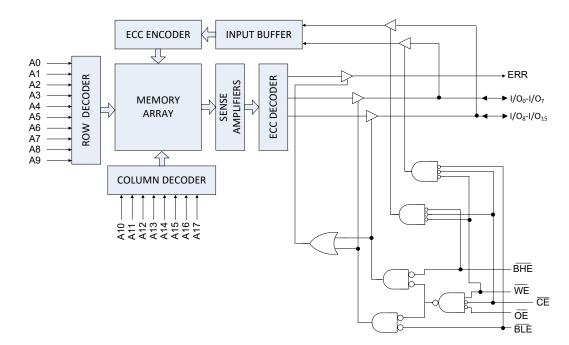
San Jose, CA 95134-1709 • 408-943-2600 Revised July 13, 2018



Logic Block Diagram – CY7C1041G



Logic Block Diagram – CY7C1041GE





Contents

| Pin Configurations | 4 |
|--------------------------------|----|
| Maximum Ratings | 6 |
| Operating Range | |
| DC Electrical Characteristics | |
| Capacitance | 7 |
| Thermal Resistance | 7 |
| AC Test Loads and Waveforms | 7 |
| Data Retention Characteristics | 8 |
| Data Retention Waveform | 8 |
| AC Switching Characteristics | 9 |
| Switching Waveforms | |
| Truth Table | |
| ERR Output – CY7C1041GE | 14 |
| | |

| Ordering Information | 15 |
|---|----|
| Ordering Code Definitions | 16 |
| Package Diagrams | 17 |
| Acronyms | 19 |
| Document Conventions | 19 |
| Units of Measure | 19 |
| Document History Page | 20 |
| Sales, Solutions, and Legal Information | 21 |
| Worldwide Sales and Design Support | 21 |
| Products | 21 |
| PSoC® Solutions | 21 |
| Cypress Developer Community | 21 |
| Technical Support | |



Pin Configurations

Figure 1. 48-ball VFBGA (6 × 8 × 1.0 mm) Single Chip Enable Figure 2. 48-ball VFBGA (6 × 8 × 1.0 mm) Single Chip Enable without ERR, CY7C1041G^[5], Package/Grade ID: BVXI^[7] with ERR, CY7C1041GE^[5, 6], Package/Grade ID: BVXI^[7]

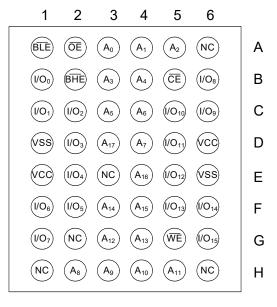
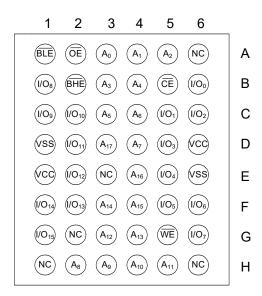


Figure 3. 48-ball VFBGA (6 × 8 × 1.0 mm) Single Chip Enable without ERR, CY7C1041G ^[5], Package/Grade ID: BVJXI ^[7]



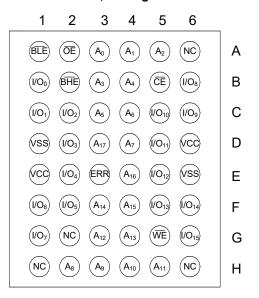
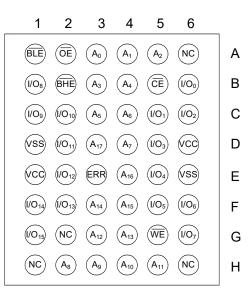


Figure 4. 48-ball VFBGA (6 × 8 × 1.0 mm) Single Chip Enable with ERR, CY7C1041GE ^[5, 6], Package/Grade ID: BVJXI ^[7]



Notes

- 5. NC pins are not connected internally to the die.
- 6. ERR is an output pin.
- Package type BVJXI is JEDEC compliant compared to package type BVXI. The difference between the two is that the higher and lower byte I/Os (I/O_[7:0] and I/O_[15:8] balls are swapped.



Pin Configurations (continued)

Figure 5. 44-pin TSOP II/44-pin SOJ Single Chip Enable with ERR, CY7C1041GE ^[8, 9]

| A0 = | 1 | \cup | 44 | A17 |
|---------------|----------|---------------|-------------------|-------|
| A1 | 2 | | 43 | A16 |
| A2 | 3 | | 42 | A15 |
| A3 = | 4 | | 41 | /OE |
| A4 🗖 | 5 | | 40 | /BHE |
| /CE | 6 | | 39 | /BLE |
| I/O0 = | 7 | | 38 | I/O15 |
| I/O1 ⊟ | 8 | | 37 | I/O14 |
| I/O2 | 9 | 44- pin TSOP | 1 <mark>36</mark> | I/O13 |
| I/O3 □ | 10 | 44- piil 1001 | '' 35 | I/O12 |
| VCC | 11 | | 34 | VSS |
| VSS■ | 12 | | 33 | VCC |
| I/O4 ■ | 13 | | 32 | I/011 |
| I/O5 🗖 | 14 | | 31 | I/O10 |
| I/O6 🗖 | 15 | | 30 | I/O9 |
| I/07 🗖 | 16 | | 29 | I/O8 |
| /WE | 17 | | 28 | ERR |
| A5🖿 | 18 | | 27 | A14 |
| A6 🗖 | 19 | | 26 | A13 |
| A7 🗖 | 20 | | 25 | A12 |
| A8 🗖 | 21 | | 24 | A11 |
| A9 = | 22 | | 23 | A10 |
| | | | | |

Figure 6. 44-pin TSOP II/44-pin SOJ Single Chip Enable without ERR, CY7C1041G ^[8]

| | | | | 1 |
|--------|----|----------------|----|---------------|
| A0 🗖 | 1 | - | 44 | A 17 |
| A1 🗖 | 2 | | 43 | a A16 |
| A2 🗖 | 3 | | 42 | a A15 |
| A3 🗖 | 4 | | 41 | I /OE |
| A4 🗖 | 5 | | 40 | b /BHE |
| /CE 🗖 | 6 | | 39 | JBLE |
| I/O0 🗖 | 7 | | 38 | I /O15 |
| I/O1 🗖 | 8 | | 37 | I /014 |
| I/O2 🗖 | 9 | 44-pin TSOP II | 36 | I /O13 |
| I/O3 🗖 | 10 | | 35 | I /012 |
| VCC 🗖 | 11 | | 34 | ■ VSS |
| VSS 🗖 | 12 | | 33 | |
| I/O4 🗖 | 13 | | 32 | I /011 |
| I/O5 🗖 | 14 | | 31 | I /O10 |
| I/O6 🗖 | 15 | | 30 | I /O9 |
| I/07 🗖 | 16 | | 29 | = 1/08 |
| /WE 🗖 | 17 | | 28 | NC I |
| A5 🗖 | 18 | | 27 | A 14 |
| A6 🗖 | 19 | | 26 | P A13 |
| A7 🗖 | 20 | | 25 | A 12 |
| A8 🗖 | 21 | | 24 | A 11 |
| A9 🗖 | 22 | | 23 | A 10 |

Notes

8. NC pins are not connected internally to the die.

9. ERR is an output pin.



Maximum Ratings

Exceeding maximum ratings may impair the useful life of the device. These user guidelines are not tested.

| Storage temperature65 °C to +150 °C |
|---|
| Ambient temperature with power applied |
| Supply voltage on V_{CC} relative to GND $^{[10]}$ –0.5 V to V_{CC} + 0.5 V |
| DC voltage applied to outputs in HI-Z State $^{[10]}$ 0.5 V to V_{CC} + 0.5 V |

| DC input voltage ^[10] | –0.5 V to V_{CC} + 0.5 V |
|-------------------------------------|----------------------------|
| Current into outputs (in LOW state) | 20 mA |
| Static discharge voltage | |
| (MIL-STD-883, Method 3015) | >2001 V |
| Latch-up current | > 140 mA |

Operating Range

| Grade | Ambient Temperature | V _{cc} |
|------------|---------------------|---|
| Industrial | –40 °C to +85 °C | 1.65 V to 2.2 V, 2.2 V to 3.6 V, 4.5 V to 5.5 V |

DC Electrical Characteristics

Over the operating range of -40 °C to 85 °C

| Parameter | Deeg | rintion | Test Canditions | 1 | 0 ns/15 n | s | Unit |
|------------------|------------------------------------|--------------------|---|--------------------------------------|-----------|---------------------------------------|------|
| Parameter | Desc | ription | Test Conditions | Min | Тур [11] | Max | Unit |
| V _{OH} | Output HIGH | 1.65 V to 2.2 V | V _{CC} = Min, I _{OH} = –0.1 mA | 1.4 | _ | _ | V |
| | voltage | 2.2 V to 2.7 V | V _{CC} = Min, I _{OH} = –1.0 mA | 2 | _ | - | |
| | | 2.7 V to 3.0 V | V _{CC} = Min, I _{OH} = –4.0 mA | 2.2 | _ | - | |
| | | 3.0 V to 3.6 V | V _{CC} = Min, I _{OH} = –4.0 mA | 2.4 | - | - | |
| | | 4.5 V to 5.5 V | V _{CC} = Min, I _{OH} = –4.0 mA | 2.4 | - | - | |
| | | 4.5 V to 5.5 V | V _{CC} = Min, I _{OH} = –0.1 mA | V _{CC} -0.5 ^[12] | _ | _ | |
| V _{OL} | Output LOW | 1.65 V to 2.2 V | V _{CC} = Min, I _{OL} = 0.1 mA | - | - | 0.2 | V |
| | voltage | 2.2 V to 2.7 V | V _{CC} = Min, I _{OL} = 2 mA | - | _ | 0.4 | |
| | | 2.7 V to 3.6 V | V _{CC} = Min, I _{OL} = 8 mA | - | _ | 0.4 | |
| | | 4.5 V to 5.5 V | V _{CC} = Min, I _{OL} = 8 mA | - | _ | 0.4 | |
| V _{IH} | Input HIGH | 1.65 V to 2.2 V | _ | 1.4 | _ | V _{CC} + 0.2 ^[10] | V |
| | voltage | 2.2 V to 2.7 V | _ | 2 | _ | V _{CC} + 0.3 ^[10] | |
| | | 2.7 V to 3.6 V | _ | 2 | _ | V _{CC} + 0.3 ^[10] | |
| | | 4.5 V to 5.5 V | _ | 2 | _ | V _{CC} + 0.5 ^[10] | |
| V _{IL} | Input LOW | 1.65 V to 2.2 V | _ | -0.2 ^[10] | _ | 0.4 | V |
| | voltage | 2.2 V to 2.7 V | _ | -0.3 ^[10] | _ | 0.6 | |
| | | 2.7 V to 3.6 V | _ | -0.3 ^[10] | _ | 0.8 | |
| | | 4.5 V to 5.5 V | | -0.5 ^[10] | _ | 0.8 | |
| I _{IX} | Input leakage cu | urrent | $GND \leq V_{IN} \leq V_{CC}$ | -1 | _ | +1 | μA |
| I _{OZ} | Output leakage | current | GND <u><</u> V _{OUT} <u><</u> V _{CC} , Output disabled | -1 | _ | +1 | μA |
| I _{CC} | Operating suppl | y current | Max V _{CC} , I _{OUT} = 0 mA, f = 100 MHz CMOS levels | - | 38 | 45 | mA |
| | | | CMOS levels f = 66.7 MHz | - | _ | 40 | |
| I _{SB1} | Automatic CE p current – TTL in | ower-down iputs | $\begin{array}{l} \text{Max V}_{\text{CC}}, \ \overline{\text{CE}} \geq \text{V}_{\text{IH}}, \\ \text{V}_{\text{IN}} \geq \text{V}_{\text{IH}} \text{ or } \text{V}_{\text{IN}} \leq \text{V}_{\text{IL}}, \ \text{f} = \text{f}_{\text{MAX}} \end{array}$ | - | _ | 15 | mA |
| I _{SB2} | Automatic CE p current – CMOS | | $\begin{array}{l} \text{Max V}_{\text{CC}}, \ \overline{\text{CE}} \geq \text{V}_{\text{CC}} - 0.2 \text{ V}, \\ \text{V}_{\text{IN}} \geq \text{V}_{\text{CC}} - 0.2 \text{ V} \text{ or } \text{V}_{\text{IN}} \leq 0.2 \text{ V}, \text{ f} = 0 \end{array}$ | - | 6 | 8 | mA |

Notes

10. $V_{IL(min)}$ = -2.0 V and $V_{IH(max)}$ = V_{CC} + 2 V for pulse durations of less than 20 ns.

11. Typical values are included for reference only and are not guaranteed or tested. Typical values are measured at V_{CC} = 1.8 V (for V_{CC} range of 1.65 V – 2.2 V), V_{CC} = 3 V (for V_{CC} range of 2.2V – 3.6 V), and V_{CC} = 5 V (for V_{CC} range of 4.5 V – 5.5 V), T_A = 25 °C.

12. This parameter is guaranteed by design and not tested.



Capacitance

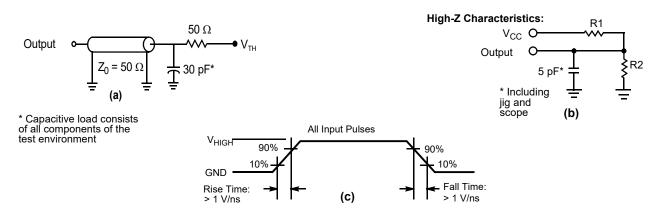
| Parameter ^[13] | Description | Test Conditions | 48-ball VFBGA | 44-pin SOJ | 44-pin TSOP II | Unit |
|---------------------------|-------------------|------------------------------------|---------------|------------|----------------|------|
| C _{IN} | Input capacitance | T _A = 25 °C, f = 1 MHz, | 10 | 10 | 10 | pF |
| C _{OUT} | I/O capacitance | $V_{CC} = V_{CC(typ)}$ | 10 | 10 | 10 | pF |

Thermal Resistance

| Parameter ^[13] | Description | Test Conditions | 48-ball VFBGA | 44-pin SOJ | 44-pin TSOP II | Unit |
|---------------------------|--|--|---------------|------------|----------------|------|
| - JA | (junction to ambient) | Still air, soldered on a 3 × 4.5 inch, four-layer | 31.35 | 55.37 | 68.85 | °C/W |
| 30 | Thermal resistance (junction to case) | printed circuit board | 14.74 | 30.41 | 15.97 | °C/W |

AC Test Loads and Waveforms

Figure 7. AC Test Loads and Waveforms ^[14]



| Parameters | 1.8 V | 3.0 V | 5.0 V | Unit |
|-------------------|-------|-------|-------|------|
| R1 | 1667 | 317 | 317 | Ω |
| R2 | 1538 | 351 | 351 | Ω |
| V _{TH} | 0.9 | 1.5 | 1.5 | V |
| V _{HIGH} | 1.8 | 3 | 3 | V |

Notes

13. Tested initially and after any design or process changes that may affect these parameters.

14. Full-device AC operation assumes a 100-µs ramp time from 0 to V_{CC(min)} and a 100-µs wait time after V_{CC} stabilization.



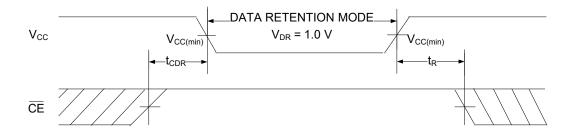
Data Retention Characteristics

Over the operating range of -40 °C to 85 °C

| Parameter | Description | Conditions | Min | Max | Unit |
|------------------------------------|--------------------------------------|---|-----|-----|------|
| V _{DR} | V_{CC} for data retention | | 1 | - | V |
| I _{CCDR} | Data retention current | $V_{CC} = 1.2 \text{ V}, \overline{CE} \ge V_{CC} - 0.2 \text{ V}^{[15]},$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}, \text{ or } V_{IN} \le 0.2 \text{ V}$ | - | 8 | mA |
| t _{CDR} ^[16] | Chip deselect to data retention time | | 0 | _ | ns |
| t _R ^[15, 16] | Operation recovery time | $V_{CC} \ge 2.2 V$ | 10 | - | ns |
| | | V _{CC} < 2.2 V | 15 | - | ns |

Data Retention Waveform

Figure 8. Data Retention Waveform ^[15]



Notes

15. Full-device operation requires linear V_{CC} ramp from V_{DR} to V_{CC(min)} \ge 100 µs or stable at V_{CC (min)} \ge 100 µs.

16. These parameters are guaranteed by design.



AC Switching Characteristics

Over the operating range of -40 °C to 85 °C

| Parameter [17] | Description | 10 | ns | 15 ns | | Unit |
|----------------------------|--|-----|-----|-------|-----|------|
| Parameter 111 | Description | Min | Max | Min | Max | |
| Read Cycle | | | | | • | |
| t _{RC} | Read cycle time | 10 | _ | 15 | - | ns |
| t _{AA} | Address to data / ERR valid | - | 10 | _ | 15 | ns |
| t _{OHA} | Data / ERR hold from address change | 3 | _ | 3 | - | ns |
| t _{ACE} | CE LOW to data / ERR valid | - | 10 | _ | 15 | ns |
| t _{DOE} | OE LOW to data / ERR valid | _ | 4.5 | _ | 8 | ns |
| t _{LZOE} | OE LOW to low impedance ^[18] | 0 | - | 0 | _ | ns |
| t _{HZOE} | OE HIGH to HI-Z ^[18, 19] | _ | 5 | _ | 8 | ns |
| t _{LZCE} | CE LOW to low impedance ^[18] | 3 | - | 3 | _ | ns |
| t _{HZCE} | CE HIGH to HI-Z ^[18, 19] | _ | 5 | _ | 8 | ns |
| t _{PU} | CE LOW to power-up ^[19, 18] | 0 | - | 0 | - | ns |
| t _{PD} | CE HIGH to power-down ^[19, 18] | _ | 10 | _ | 15 | ns |
| t _{DBE} | Byte enable to data valid | _ | 4.5 | _ | 8 | ns |
| t _{LZBE} | Byte enable to low impedance ^[18] | 0 | - | 0 | - | ns |
| t _{HZBE} | Byte disable to HI-Z ^[19] | _ | 6 | _ | 8 | ns |
| Write Cycle ^{[20} | 0, 21] | Ι | 1 | 1 | | |
| t _{WC} | Write cycle time | 10 | - | 15 | - | ns |
| t _{SCE} | CE LOW to write end | 7 | - | 12 | - | ns |
| t _{AW} | Address setup to write end | 7 | - | 12 | _ | ns |
| t _{HA} | Address hold from write end | 0 | - | 0 | - | ns |
| t _{SA} | Address setup to write start | 0 | - | 0 | - | ns |
| t _{PWE} | WE pulse width | 7 | - | 12 | - | ns |
| t _{SD} | Data setup to write end | 5 | - | 8 | - | ns |
| t _{HD} | Data hold from write end | 0 | - | 0 | - | ns |
| t _{LZWE} | WE HIGH to low impedance ^[18] | 3 | - | 3 | - | ns |
| t _{HZWE} | WE LOW to HI-Z ^[19] | _ | 5 | _ | 8 | ns |
| t _{BW} | Byte Enable to write end | 7 | _ | 12 | - | ns |

Notes

19. These parameters are guaranteed by design and are not tested.

20. The internal write time of the memory is defined by the overlap of $\overline{WE} = V_{IL}$, $\overline{CE} = V_{IL}$, and \overline{BHE} or $\overline{BLE} = V_{IL}$. These signals must be LOW to initiate a write, and the HIGH transition of any of these signals can terminate the operation. The input data setup and hold timing should be referenced to the edge of the signal that terminates the write.

21. The minimum write cycle pulse width in Write Cycle No 2 (WE Controlled, OE LOW) should be equal to sum of t_{sd}and t_{HZWE}.

^{17.} Test conditions assume a signal transition time (rise/fall) of 3 ns or less, timing reference levels of 1.5 V (for $V_{CC} \ge 3$ V) and $V_{CC}/2$ (for $V_{CC} \le 3$ V), and input pulse levels of 0 to 3 V (for $V_{CC} \ge 3$ V) and 0 to V_{CC} (for $V_{CC} \le 3$ V). Test conditions for the read cycle use output loading, as shown in part (a) of Figure 7 on page 7, unless specified otherwise

^{18.} t_{HZOE}, t_{HZCE}, t_{HZVE}, t_{HZDE}, t_{LZOE}, t_{LZOE}, t_{LZOE}, t_{LZOE}, and t_{LZBE} are specified with a load capacitance of 5 pF, as shown in part (b) of Figure 7 on page 7. Transition is measured ±200 mV from steady state voltage.



Switching Waveforms



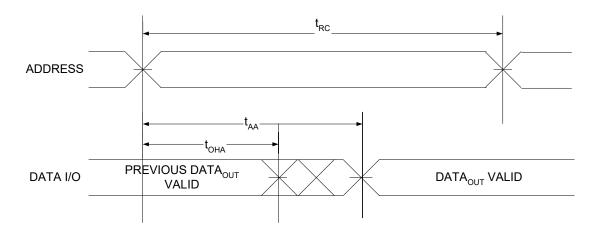
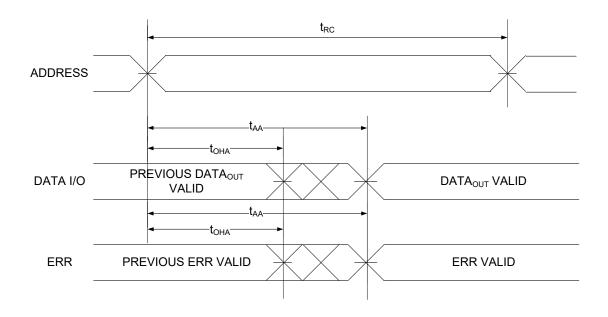


Figure 10. Read Cycle No. 1 of CY7C1041GE (Address Transition Controlled) ^[22, 23]



Notes 22. The device is continuously selected, $\overline{OE} = V_{IL}$, $\overline{CE} = V_{IL}$, \overline{BHE} or \overline{BLE} or both = V_{IL} . 23. \overline{WE} is HIGH for the read cycle.



Switching Waveforms (continued)

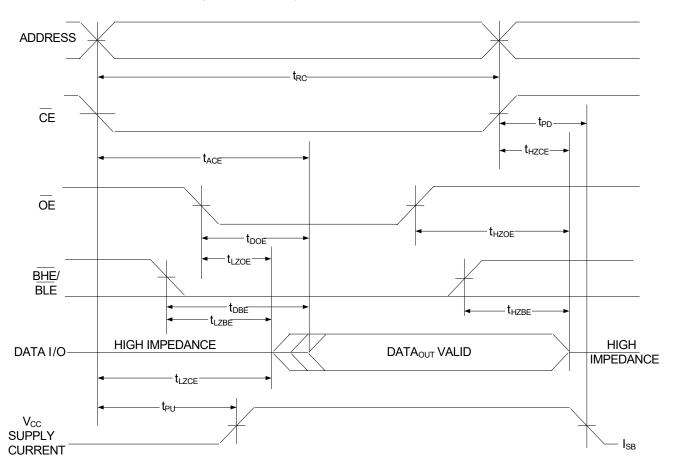


Figure 11. Read Cycle No. 2 (OE Controlled) ^[24, 25]

Notes24. WE is HIGH for the read cycle.25. Address valid prior to or coincident with \overline{CE} LOW transition.



Switching Waveforms (continued)

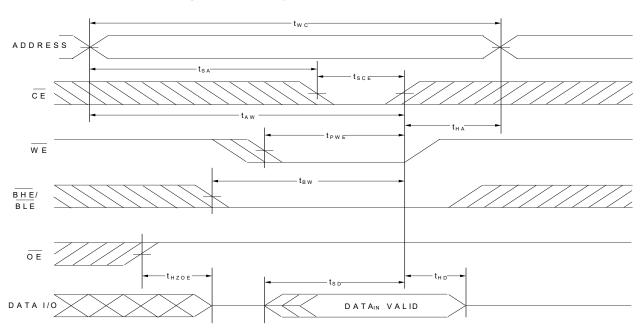
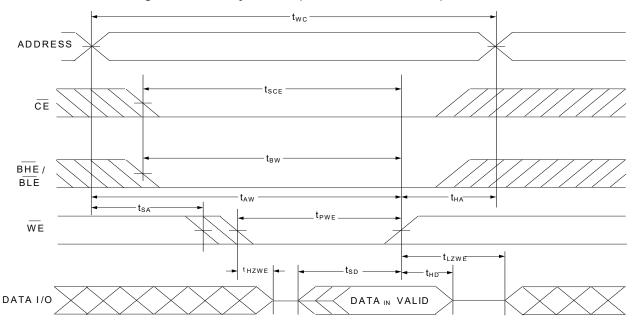


Figure 12. Write Cycle No. 1 (CE Controlled) ^[26, 27]

Figure 13. Write Cycle No. 2 ($\overline{\text{WE}}$ Controlled, $\overline{\text{OE}}$ LOW) [26, 27, 28]

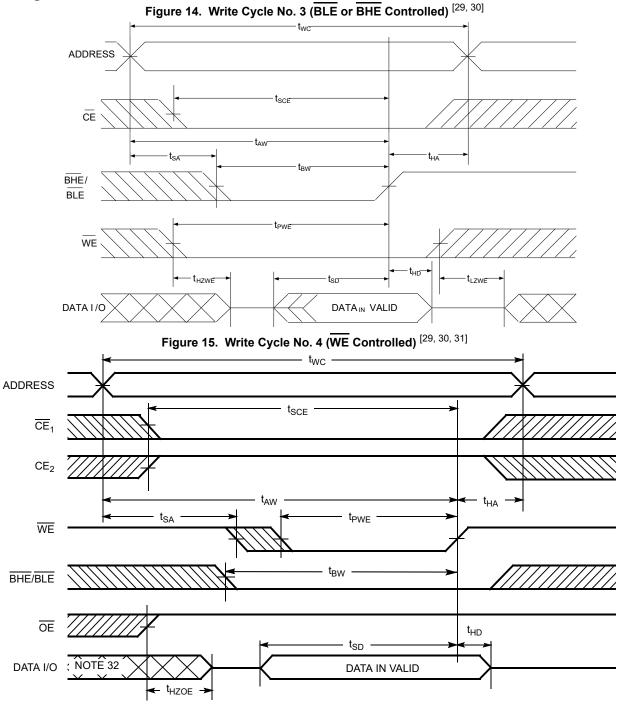


Notes

- 26. The internal write time of the memory is defined by the overlap of WE = V_{IL}, CE = V_{IL}, and BHE or BLE = V_{IL}. These signals must be LOW to initiate a write, and the HIGH transition of any of these signals can terminate the operation. The input data setup and hold timing should be referenced to the edge of the signal that terminates the write.
- 27. Data I/O is in HI-Z state if $\overline{CE} = V_{IH}$, or $\overline{OE} = V_{IH}$, or \overline{BHE} , and/or $\overline{BLE} = V_{IH}$.
- 28. The minimum write cycle pulse width should be equal to sum of t_{SD} and t_{HZWE} .



Switching Waveforms (continued)



Notes

- 29. The internal write time of the memory is defined by the overlap of $\overline{WE} = V_{IL}$, $\overline{CE} = V_{IL}$, and \overline{BHE} or $\overline{BLE} = V_{IL}$. These signals must be LOW to initiate a write, and the HIGH transition of any of these signals can terminate the operation. The input data setup and hold timing should be referenced to the edge of the signal that terminates the write.
- 30. Data I/O is in HI-Z state if $\overline{CE} = V_{IH}$, or $\overline{OE} = V_{IH}$, or \overline{BHE} , and/or $\overline{BLE} = V_{IH}$.
- 31. Data I/O is high impedance if $\overline{OE} = V_{IH}$.
- 32. During this period the I/Os are in output state. Do not apply input signals.



Truth Table

| CE | OE | WE | BLE | BHE | I/O ₀ –I/O ₇ | I/O ₈ –I/O ₁₅ | Mode | Power |
|----|-------------------|-------------------|-------------------|-------------------|------------------------------------|-------------------------------------|----------------------------|----------------------------|
| Н | X ^[33] | X ^[33] | X ^[33] | X ^[33] | HI-Z | HI-Z | Power down | Standby (I _{SB}) |
| L | L | Н | L | L | Data out | Data out | Read all bits | Active (I _{CC}) |
| L | L | Н | L | Н | Data out | HI-Z | Read lower bits only | Active (I _{CC}) |
| L | L | Н | Н | L | HI-Z | Data out | Read upper bits only | Active (I _{CC}) |
| L | Х | L | L | L | Data in | Data in | Write all bits | Active (I _{CC}) |
| L | Х | L | L | Н | Data in | HI-Z | Write lower bits only | Active (I _{CC}) |
| L | Х | L | Н | L | HI-Z | Data in | Write upper bits only | Active (I _{CC}) |
| L | Н | Н | Х | Х | HI-Z | HI-Z | Selected, outputs disabled | Active (I _{CC}) |
| L | Х | Х | Н | Н | HI-Z | HI-Z | Selected, outputs disabled | Active (I _{CC}) |

ERR Output – CY7C1041GE

| Output ^[34] | Mode | | | |
|------------------------|--|--|--|--|
| 0 | Read operation, no single-bit error in the stored data. | | | |
| 1 | Read operation, single-bit error detected and corrected. | | | |
| HI-Z | Device deselected or outputs disabled or Write operation | | | |

 $[\]begin{array}{l} \textbf{Notes}\\ 33. \mbox{ The input voltage levels on these pins should be either at V_{IH} or V_{IL}.\\ 34. \mbox{ ERR is an Output pin.If not used, this pin should be left floating.} \end{array}$

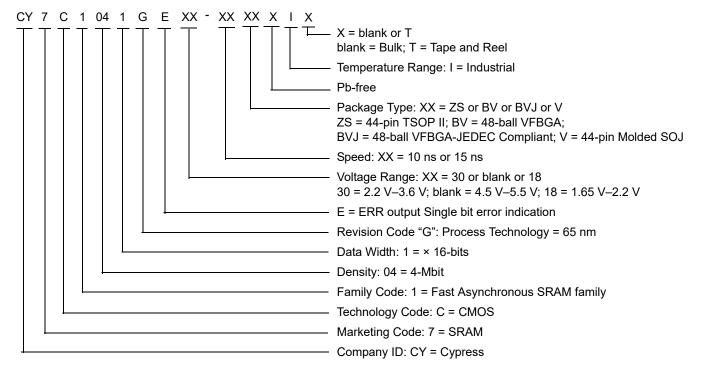


Ordering Information

| Speed (ns) | Voltage Range | Ordering Code | Package Diagram | Package Type (all Pb-free) | Operating Range |
|---------------|------------------|----------------------|--------------------|--|--------------------|
| 10 | 2.2 V–3.6 V | CY7C1041GE30-10ZSXI | 51-85087 | 44-pin TSOP II, ERR output | Industrial |
| | | CY7C1041GE30-10ZSXIT | 51-85087 | 44-pin TSOP II, ERR output, Tape and Reel | |
| | | CY7C1041G30-10ZSXI | 51-85087 | 44-pin TSOP II | |
| | | CY7C1041G30-10ZSXIT | 51-85087 | 44-pin TSOP II, Tape and Reel | |
| | | CY7C1041GE30-10BVXI | 51-85150 | 48-ball VFBGA (6 × 8 × 1.0 mm), ERR output | |
| | | CY7C1041GE30-10BVXIT | 51-85150 | 48-ball VFBGA (6 × 8 × 1.0 mm), ERR output, Tape and Reel | |
| | | CY7C1041G30-10BVXI | 51-85150 | 48-ball VFBGA (6 × 8 × 1.0 mm) | |
| | | CY7C1041G30-10BVXIT | 51-85150 | 48-ball VFBGA (6 × 8 × 1.0 mm), Tape and Reel | |
| | | CY7C1041G30-10BVJXI | 51-85150 | 48-ball VFBGA (6 × 8 × 1.0 mm), JEDEC | |
| | | CY7C1041G30-10BVJXIT | 51-85150 | 48-ball VFBGA (6 × 8 × 1.0 mm), JEDEC, Tape and Reel | |
| | | CY7C1041G30-10VXI | 51-85082 | 44-pin SOJ (400 Mils) | |
| | | CY7C1041G30-10VXIT | 51-85082 | 44-pin SOJ (400 Mils), Tape and Reel | |
| | | CY7C1041GE30-10VXI | 51-85082 | 44-pin SOJ (400 Mils), ERR output | |
| | | CY7C1041GE30-10VXIT | 51-85082 | 44-pin SOJ (400 Mils), ERR output, Tape and Reel | |
| | 4.5 V–5.5 V | CY7C1041G-10ZSXI | 51-85087 | 44-pin TSOP II | |
| | | CY7C1041G-10ZSXIT | 51-85087 | 44-pin TSOP II, Tape and Reel | |
| | | CY7C1041GE-10ZSXI | 51-85087 | 44-pin TSOP II, ERR output | |
| | | CY7C1041GE-10ZSXIT | 51-85087 | 44-pin TSOP II, ERR output, Tape and Reel | |
| | | CY7C1041GE-10VXI | 51-85082 | 44-pin SOJ (400 Mils), ERR output | |
| | | CY7C1041GE-10VXIT | 51-85082 | 44-pin SOJ (400 Mils), ERR output, Tape and Reel | |
| | | CY7C1041G-10VXI | 51-85082 | 44-pin SOJ (400 Mils) | |
| | | CY7C1041G-10VXIT | 51-85082 | 44-pin SOJ (400 Mils), Tape and Reel | |
| 15 | 1.65 V–2.2 V | CY7C1041G18-15ZSXI | 51-85087 | 44-pin TSOP II | |
| | | CY7C1041G18-15ZSXIT | 51-85087 | 44-pin TSOP II, Tape and Reel | |
| | | CY7C1041G18-15VXI | 51-85082 | 44-pin SOJ (400 Mils) | |
| | | CY7C1041G18-15VXIT | 51-85082 | 44-pin SOJ (400 Mils), Tape and Reel | |
| | | CY7C1041G18-15BVXI | 51-85150 | 48-ball VFBGA (6 × 8 × 1.0 mm) | |
| | | CY7C1041G18-15BVXT | 51-85150 | 48-ball VFBGA (6 × 8 × 1.0 mm), Tape and Reel | |

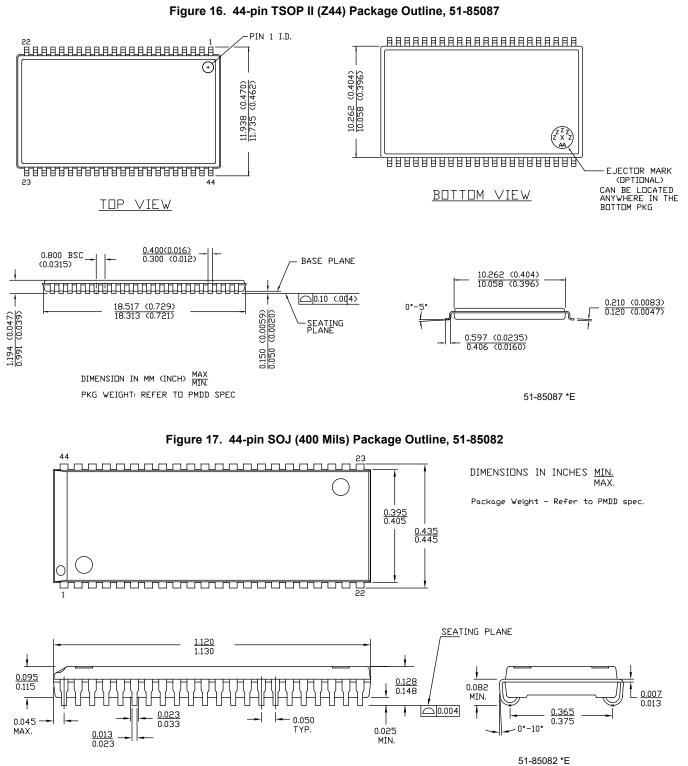


Ordering Code Definitions





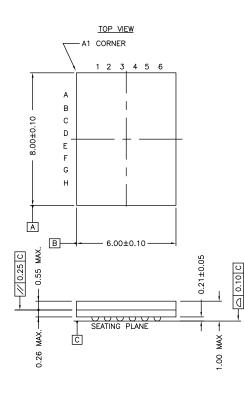
Package Diagrams

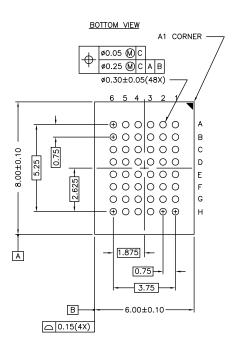




Package Diagrams (continued)

Figure 18. 48-ball VFBGA (6 × 8 × 1.0 mm) BV48/BZ48 Package Outline, 51-85150





NOTE:

PACKAGE WEIGHT: See Cypress Package Material Declaration Datasheet (PMDD) posted on the Cypress web.

51-85150 *H



Acronyms

| Acronym | Description | | |
|---------|---|--|--|
| BHE | byte high enable | | |
| BLE | byte low enable | | |
| CE | chip enable | | |
| CMOS | complementary metal oxide semiconductor | | |
| I/O | input/output | | |
| OE | output enable | | |
| SRAM | static random access memory | | |
| TSOP | thin small outline package | | |
| TTL | transistor-transistor logic | | |
| VFBGA | very fine-pitch ball grid array | | |
| WE | write enable | | |

Document Conventions

Units of Measure

| Symbol | Unit of Measure |
|--------|-----------------|
| °C | Degrees Celsius |
| MHz | megahertz |
| μA | microamperes |
| μs | microseconds |
| mA | milliamperes |
| mm | millimeters |
| ns | nanoseconds |
| Ω | ohms |
| % | percent |
| pF | picofarads |
| V | volts |
| W | watts |



Document History Page

| Document Document | Document Title: CY7C1041G/CY7C1041GE, 4-Mbit (256K words × 16-bit) Static RAM with Error-Correcting Code (ECC) Document Number: 001-91368 | | | | |
|----------------------|--|--------------------|--------------------|--|--|
| Rev. | ECN No. | Orig. of Change | Submission Date | Description of Change | |
| *F | 4867081 | NILE | 07/31/2015 | Changed status from Preliminary to Final. | |
| *G | 4876251 | NILE | 08/07/2015 | Updated Ordering Information: Updated part numbers. | |
| *H | 4968879 | NILE | 10/16/2015 | Fixed typo in bookmarks. | |
| * | 5019226 | VINI | 11/18/2015 | Updated Ordering Information: Updated part numbers. | |
| *J | 5122043 | NILE | 02/02/2016 | Updated Truth Table. | |
| *К | 5223335 | NILE | 08/30/2016 | Updated DC Electrical Characteristics: Removed values of V _{OH} parameter corresponding to "2.7 V to 3.6 V" range. Added values of V _{OH} parameter corresponding to "2.7 V to 3.0 V" and "3.0 V to 3.6 V" ranges. Updated Note 10 (Replaced "2 ns" with "20 ns"). Updated Ordering Information: Updated part numbers. Updated to new template. | |
| *L | 5655218 | NILE | 03/09/2017 | Updated Logic Block Diagram – CY7C1041G (Updated diagram to change the devices from Dual Chip enabled to Single Chip enabled). Updated Logic Block Diagram – CY7C1041GE (Updated diagram to change the devices from Dual Chip enabled to Single Chip enabled). Updated to new template. | |
| *M | 5731242 | GNKK | 05/09/2017 | Updated logo and copyright. Completing Sunset Review. | |
| *N | 6245720 | NILE | 07/13/2018 | Updated Features: Added Note 2 and referred the same note in "Embedded ECC for single-bit error correction". Updated to new template. Completing Sunset Review. | |



Sales, Solutions, and Legal Information

Worldwide Sales and Design Support

Cypress maintains a worldwide network of offices, solution centers, manufacturer's representatives, and distributors. To find the office closest to you, visit us at Cypress Locations.

Products

| Arm [®] Cortex [®] Microcontrollers | cypress.com/arm |
|---|------------------------|
| Automotive | cypress.com/automotive |
| Clocks & Buffers | cypress.com/clocks |
| Interface | cypress.com/interface |
| Internet of Things | cypress.com/iot |
| Memory | cypress.com/memory |
| Microcontrollers | cypress.com/mcu |
| PSoC | cypress.com/psoc |
| Power Management ICs | cypress.com/pmic |
| Touch Sensing | cypress.com/touch |
| USB Controllers | cypress.com/usb |
| Wireless Connectivity | cypress.com/wireless |

PSoC[®] Solutions

PSoC 1 | PSoC 3 | PSoC 4 | PSoC 5LP | PSoC 6 MCU

Cypress Developer Community Community | Projects | Video | Blogs | Training | Components

Technical Support cypress.com/support

Cypress, the Cypress logo, Spansion, the Spansion logo, and combinations thereof, WICED, PSoC, CapSense, EZ-USB, F-RAM, and Traveo are trademarks or registered trademarks of Cypress in the United States and other countries. For a more complete list of Cypress trademarks, visit cypress.com. Other names and brands may be claimed as property of their respective owners.

[©] Cypress Semiconductor Corporation, 2014–2018. This document is the property of Cypress Semiconductor Corporation and its subsidiaries, including Spansion LLC ("Cypress"). This document, including any software or firmware included or referenced in this document ("Software"), is owned by Cypress under the intellectual property laws and treaties of the United States and other countries worldwide. Cypress reserves all rights under such laws and treaties and does not, except as specifically stated in this paragraph, grant any license under its patents, copyrights, trademarks, or other intellectual property rights. If the Software is not accompanied by a license agreement and you do not otherwise have a written agreement with Cypress governing the use of the Software, then Cypress hereby grants you a personal, non-exclusive, nontransferable license (without the right to sublicense) (1) under its copyright rights in the Software (a) for Software provided in source code form, to modify and reproduce the Software solely for use with Cypress hardware products, only internally within your organization, and (b) to distribute the Software in binary code form externally to end users (either directly or indirectly through resellers and distributors), solely for use on Cypress hardware product units, and (2) under those claims of Cypress's patents that are infringed by the Software (as provided by Cypress, unmodified) to make, use, distribute, and import the Software solely for use with Cypress hardware products. Any other use, reproduction, modification, translation, or compilation of the Software is prohibited.

TO THE EXTENT PERMITTED BY APPLICABLE LAW, CYPRESS MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARD TO THIS DOCUMENT OR ANY SOFTWARE OR ACCOMPANYING HARDWARE, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE. No computing device can be absolutely secure. Therefore, despite security measures implemented in Cypress hardware or software products, Cypress does not assume any liability arising out of any security breach, such as unauthorized access to or use of a Cypress product. In addition, the products described in these materials may contain design defects or errors known as errata which may cause the product to deviate from published specifications. To the extent permitted by applicable law, Cypress reserves the right to make changes to this document without further notice. Cypress does not assume any liability arising out of the application or use of any product or circuit described in this document. Any information provided in this document, including any sample design information or programming code, is provided only for reference purposes. It is the responsibility of the user of this document to properly design, program, and test the functionality and safety of any application made of this information and any resulting product. Cypress products are not designed, intended, or authorized for use as critical components in systems designed or intended for the operation of weapons, weapons systems, nuclear installations, life-support devices or system could cause personal injury, death, or properly damage ("Unintended Uses"). A critical component is any component of a device or system whose failure to perform can be reasonably expected to cause the failure of the device or system, or to affect its safety or effectiveness. Cypress is not liable, in whole or in part, and you shall and hereby do release Cypress from any claim, damage, or other liability arising from or related to any Unintended Uses of Cypress products.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Cypress Semiconductor:

 CY7C1041G-10ZSXIT
 CY7C1041GE-10VXI
 CY7C1041GE-10ZSXI
 CY7C1041G18-15ZSXI
 CY7C1041GE30-10VXI

 CY7C1041G30-10VXIT
 CY7C1041G30-10ZSXIT
 CY7C1041G30-10BVJXIT
 CY7C1041G-10VXIT
 CY7C1041G30-10VXIT

 10BVXIT
 CY7C1041GE30-10ZSXIT
 CY7C1041G30-10ZSXIT
 CY7C1041G30-10VXIT
 CY7C1041G-10VXIT
 CY7C1041G30-10VXIT